NSN 5961-01-079-4504

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-079-4504 **Inclosure Material:** Glass **Overall Length:** Between 0.130 inches and 0.260 inches **Terminal Length:** Between 0.900 inches and 1.250 inches **Overall Diameter:** Between 0.145 inches and 0.250 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 50.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Item must comply with requirements of defense electronics supply center production standard no. L02795; for navy nuclear propulsion plant products only; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: